GE Grid Solutions

Reason MU320 Extended Version

Analog and digital, fast and accurate: Process Interface Unit for Digital Substations

MU320E is the Process Interface Unit (PIU) with analog and binary interfaces for full switchyard modelling, control and digitization using IEC 61850 standards and protocols such as Sampled Values (SV) and GOOSE.

The MU320E unlocks the full value of a completely digital substation, acting as the I/O interface to every bay IED, particularly for protective relays and bay control units. Limiting the field wiring just up to the MU320E reduces project complexity by reducing cabling and physical connections. Bay IEDs can use data from redundant MU320E units, increasing system availability. Bay IEDs can also be quickly replaced as no field wiring is involved. The MU320E has the additional benefit of improving CT performance and cost through a lower connected burden and a reduction in the number of CT cores required for an application.

Key Benefits

- Compact form factor supports field installation options into circuit breakers cabinets, marshalling kiosks and metal-clad switchgear.
- 6 slots for I/O cards allows multiple applications. Apply as Merging Unit, Remote I/O device or PIU. Right size and point count for all type of application.
- High Speed High Break output contact option to directly operate into Circuit Breakers and Switchgears.
- Card slots for 2 CT/VT analog boards supports application on breaker-and-a-half lines, dual distribution feeders, and combination protection and metering installations.
- Optional metering accuracy CT/VT analog board for revenue metering and power quality applications.
- 2 SV streams possible (one per CT/VT analog board). Each stream can be protection (80 s/c) or power quality (256 s/c) SV streams.
- Full integration into the digital substation through 2 Ethernet ports, support for Parallel Redundancy Protocol (PRP) high availability networks, and IEEE 1588 Precision Time Protocol.
- Full IEC 61850 Edition 2, including support for Test mode and Simulation. Multiple logical devices to integrate multiple circuit breakers and disconnectors in one MU320E.

Applications

- Process Interface Unit for full bay digitization.
- Standalone Merging Unit for conventional instrument transformers.
- Remote I/O (RIO) device for interfacing to primary equipment such as circuit breakers and disconnectors.
- Bay unit for GE B30X distributed bus bar protection system.
- Revenue accuracy and power quality metering applications.
- Breaker-and-a-half line terminals using a single PIU device.
- Two feeders in a single PIU device.



imagination at work



High I/O Density & Flexibility

- MU320E stands as a ½ 19" and low depth device, perfect to be placed in enclosure kiosks in the yard.
- Up to 6 flexible slots for Analog and Binary I/O.
- Up to 16 Analog Inputs 8CT/8VT.
- Several combination options up to 96 Binary Inputs or up 48 Binary outputs.
- A single box for Metering and Protection purposes.

Switchyard Interface

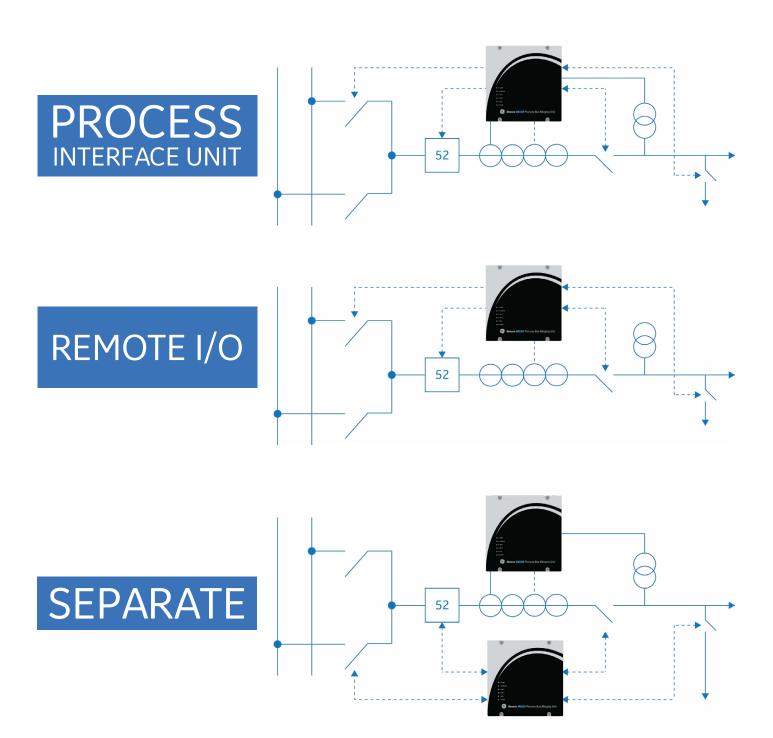
- IEC61850 dedicated data modelling for Circuit Breakers, Circuit Switches and Current and Voltage Transformers.
- Simple interface to connect Binary I/O and GOOSE points to Switchyard devices data model.

IEC 61850 Edition 2 & Test mode

- Operation modes On, Test, Blocked, Test/Blocked and Off
- Operation modes independently configurable per Logical Device (LD)

Ease-of-Use

- Clean, simple and functional IED Configurator Tool (ICT)
- Software configurable binary input voltage level
- Intuitive IEC 61113-3 based logic.



Flexibility

By integrating binary inputs, outputs and analogue connections into one box, the MU320E offers a cost-effective solution for a multitude of bay configurations. Up to two buses and two lines may be monitored per box with a flexible configuration of up to 96 binary inputs or 48 binary outputs

Future Proof and Interoperable

The MU320E complies with the IEC 61850-9-2 Light Edition (LE) implementation guideline, which guarantees its interoperability. This was tested and approved by the global testing and certification company TUV SUD according to the Implementation Guideline for Digital Interfaces to Instrument Transformers.

Furthermore, measurements of each CT/VT set may be broadcasted in protection and measurement profiles, allowing multiple protection, automation and control applications. Covering the gap between conventional and digital substations serves to future-proof substation technologies.

Test Modes

IEC 61850 edition 2 provides standard mechanisms for testing purposes, reducing commissioning complexity and allowing new bay installations without affecting substation operation.

MU320E is fully compatible to IEC 61850 ed. 2, allowing users to independently configure mode and behavior of each logical devices allowing then to operate as: *On, Test, Blocked, Test/Blocked and Off.*

A safer substation

Transmitting the instrument transformers' measurements digitally through optical fibers eliminates the risk of inadvertent mishandling of the current and voltage circuits and makes the relay room a safer work environment, eliminating hazards and reducing the risk of personnel injury.

Reduce the engineering effort and cost

The use of Process Bus with the MU320E drastically reduces the need for trenches, ducts, glands, cable trays and copper hardwiring, as the information is exchanged among IEDs using fiber optic cables and ethernet switches.

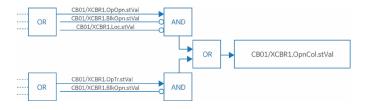
Fewer cables to manage also means reduced engineering complexity as extensive wiring schematics are replaced by standardized version-controlled configuration files. Future reconfigurations are automatically documented by the IED configuration tool.

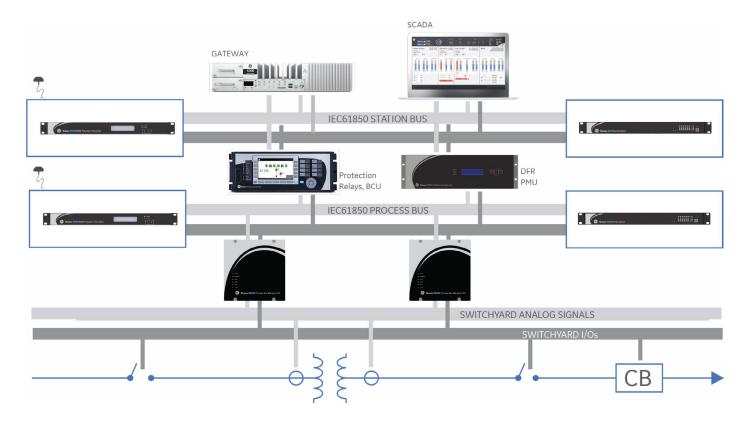
Example application of IEC 61850 Architecture

Switchyard modelling and digitization

The Process Interface Unit MU320E stands as the device responsible to be the physical to digital interface for primary equipment, including the possibility to represent them through the IEC 61850-7-4 data model, in a way that the MU320E becomes the extension of the CT/VT, circuit breakers and disconnectors through the logical nodes TCTR, TVTR, XCBR and XSWI.

Through simple user interface IEC 61113-3 based logic it is possible to connect MU320E physical and digital inputs to its data model and digital outputs, allowing the true Switchyard digitization.





Improved Reliability

Power systems applications are mission critical systems, where the industry standard is to offer inherent redundancy in the schemes applied. The Reason MU320E provides unsurpassed reliability, as a flexible, redundant solution. The Ethernet connections support the IEC standard Parallel Redundancy Protocol (PRP), where a redundant star-connected topology allows zero-time - or bumpless – recovery. The shallow case design makes it easy to deploy MU320E in main and backup, or dual main applications, each connected to different cores of the line CTs and individual protection.

MU320 is the first of its class to manage both PRP redundancy and IEEE 1588 PTP operating together in the substation architecture. Profit from a single redundant network for higher reliability in communication and synchronization simultaneously.

Functions and IEC61850 data modeling

One of the main advances brought by IEC 61850 is the way it allows the IEDs to standardize their model through elements such as *Logical Nodes* and *Control Blocks*. The main functions that the MU320E supports in this regard are:

LN	DESCRIPTION
LTMS	Time synchronization supervision
LTIM	Local time supervision
LCCH	Physical ethernet communication channel supervision
LGOS	GOOSE subscription supervision
GGIO	Generic Process I/O covering all binary I/O available
SIMG	Gas Insulation medium supervision*
SIML	Liquid Insulation medium supervision*
XCBR	Circuit Breaker modeling – Supervision and operation
XSWI	Circuit Switch modeling – Supervision and control
TCTR	Current Transformer modelling – Samples available through Sampled Values
TVTR	Voltage Transformer modelling – Samples available through Sampled Values



TECHNICAL SPECIFICATION

Power Supply 110-250 Vdc, 110- 240 Vac

Operating nominal voltage	110-250 V dc, 110- 240 V ac
Frequency	50/60 Hz ± 3Hz
Operating voltage range	88 - 300 V dc, 88 - 264 V ac
Power Consumption	MAX 20 VA
Connector	3 pin: positive (phase), negative (neutral) and ground

Optical Irig-B Input

Signal	IRIG-B004
Wavelength	820 nm
Fiber type	Multimode 62.5 / 125 µm
	ST
Connector	- 24 dBm

Serial Port

Interface	RS232 and RS485
Use	Device configuration and software upgrade
Bit Rate	115200 bps
Connector	DB9 (female), standard DTE

In Service Conta	ct	
Description	Dry contact relay, normally closed	
Switching Voltage	250 V (AC and DC)	
Permissible current continuous	5 A	
Maximum voltage	300 (AC and DC)	
Making Capacity	15 A, 4 sec	
Breaking Capacity	40W Resistive, 25 W/VA L/R = 50ms	
Dropout time	< 5 ms	
Burden	~30mA @12V [360mW]	
Withstand voltages across open contacts	1000V rms	
Permissible short time value for 0.2s	30A	
Analog Acquisiti	on	
Resolution	16 bits	
Acquisition rate	80 and 256 ppc	
Group delay	< 1.1ms	
Bandwidth	1 k Hz	

Current Input

Characteristic	Standard Input			Standard Input			High accuracy Inputs		
Nominal Current (In)	5 A			1 A			1 A		
Nominal frequency	50/60Hz		50/60Hz			50/60Hz			
	Range	Error	Phase Error	Range	Error	Phase Error	Range	Error	Phase Error
	0.05ln 0.2ln	< 2.5% rd	<+-90'(+-1.5°)	0.05ln 0.2ln	< 2.5% rd	<+-90'(+-1.5°)	0.05ln 0.2ln	< 0.6% rd	<+-15'(+-0.3°)
Accuracy	0.2ln 0.8ln	< ± 0.75% rd	< ± 45' (± 0.75°)	0.2ln 0.8ln	< ± 0.75% rd	< ± 45' (± 0.75°)	0.2ln 0.8ln	< ± 0.2% rd	< ± 8' (± 0.15°)
	0.8ln 4ln	< ± 0.5% rd	< ± 30' (± 0.5°)	0.8In 4In	< ± 0.5% rd	< ± 30' (± 0.5°)	0.8In 4In	< ± 0.1% rd	< ± 30' (± 0.1°)
	4ln 40ln	< ± 1% rd	< ± 60' (± 1.0°)	4In 40In	< ± 1% rd	< ± 60' (± 1.0°)	4ln 40ln	< ± 0.4% rd	< ± 60' (± 0.2°)
Burden In	< 0.05VA		< 0.01 VA		< 0.02 VA				
Continuous overload	20A (4 x ln)		4A (4 × In)		10 A (10 x ln)				
AC current thermal withstand 1 s (Ith rms)	200A (40 x In)		40A (40x In)		20 A (20 x ln)				
Insulation	> 2.2 kVrms		> 2.2 kVrms		> 2,2 kVrms				

* rd – Indicate errors of reading values

Voltage Inputs

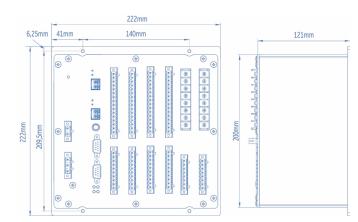
Characteristic	Standard Inputs			High accuracy Inputs			
Nominal Voltage (Vn)	115 V			115 V			
Voltage Range	10 - 460V			10 - 230V			
Nominal frequency	50/60Hz	50/60Hz					
	Range	Amplitude Error	Phase Error	Range	Amplitude Error	Phase Error	
Accuracy	0.08Vn 2Vn	< ± 0.5% rd	< ± 20' (± 0.35°)	0.08Vn 2Vn	< ± 0.1% rd	< ± 5' (± 0.1°)	
	2Vn 4Vn	< ± 1.0% rd	< ± 60' (± 1.0°)	0.08 vn 2 vn	< ± 0.1% IU	< ± 5 (± 0.1°)	
Burden Vn	< 0.1VA	< 0.1VA			< 0.1VA		
Continuous overload	230 V (2 x Vn)	230 V (2 x Vn)					
Maximum overload (1 s)	460 V (4 x Vn)	460 V (4 x Vn)			460 V (4 x Vn)		
Insulation	> 3,5 kV			> 3,5 kV			
* rd – Indicate errors of read	ling values						

Synchronization

Synchronization	
Accuracy	< 1µs
Drift when not locked	±0.016PPM (1.44 miliseconds/day)
Max Holdover	60s
Environment Con	ditions
Operating temperature (continuous)	-40 °C (-40 °F) +55°C (+131°F)
Tested as per IEC 60068-2-1:2013	-40°C (-40°F)
Tested as per IEC 60068-2-2:2013	+85°C (+185°F)
Relative humidity	0 95 %, noncondensing
Enclosure Protection II	
Front flush mounted with panel	IP40
Rear and sides	IP10
Optical Ethernet F	Ports
Interface	100BASE-FX
Bitrate	100 Mbps
Wavelength	1300 nm
Connector	LC
Fiber type	multimode 62.5 / 125 µm
Emission power	-20 dBm
Sensitivity	-32 dBm
Maximum applicable power	-14 dBm
Binary Output	
Description	Dry contact relay. Form-C or Form-A
Max. Switching Voltage	300 Vdc
Maximum continuous current	5 A
Make and short time carry current	30A, 0.2s
Breaking Capacity	40 W Resistive, 25 W/VA L/R = 50ms
Operation time	< 5 ms
Dropout time	< 15 ms
Burden	Per energized output relay: ~30mA @12V [360mW]
Protection device	MOV (Metal Oxide Varistor)
across contacts	Rated @ 250Vac/320Vdc

		Break Binary Output Form-A High Speed High Break contact				
Description	using IGB1					
Max. switching voltage	300 Vdc					
Maximum continuous current	10A	10A				
Maximum voltage	300 (AC ai	nd DC)				
Make and short time carry current	30A, 0.2s					
Breaking Capacity	Maximum	10A @ L/I	R = 40ms			
Operation time	< 0.2 ms	< 0.2 ms				
Dropout time	< 25 ms					
Burden	Per energized output relay: ~30mA @12V [360mW]					
Protection device across contacts	MOV (Metal Oxide Varistor)					
Max Number of operation	10000					
Binary Input						
Nominal Voltage	24 V	48 V	125 V	250 V		
Level Low	08 V 10 V 40 V 75 V					
Level High	17 V 19 V 85 V 160 V			160 V		
Burden	< 0.05 W	< 0.2 W	< 0.25 W	< 0.5 W		
Continuous Overload	80 V	100 V	240 V	340 V		
Dimensions and \	Neight					
Height	222 mm /	8.7 in (5 L)			

Height	222 mm / 8.7 in (5 U)
Width	222 mm / 8.7 in (½ 19")
Depth	121 mm / 4.7 in
Weight	< 3.5 kg (< 7.72 lb)



Type Test

EMC tests were performed according to IEC 60255-26 referring to the following		
IEC 61000-4-2:2008	6kV contact / 8kV air	
IEC 61000-4-3:2006	10 V/m	
IEC 61000-4-4:2012	4 kV @ 5KHz	
IEC 61000-4-5:2005	Differential mode: 4kV Common mode: 2kV	
IEC 61000-4-6:2008	10V	
IEC 61000-4-8:2009	30A/m contínuos	
IEC 61000-4-11:2004	AC dips (residual%) 0% - 1/1 cycles (50/60Hz) 40% - 50/60 cycles (50/60Hz) 70% - 25/30 cycles (50/60Hz) AC interrupt (residual%) 0% - 250/300 cycles (50/60Hz)	

IEC 61000-4-29:2000	DC dips (residual%) 0% - 10ms 40% - 200ms 70% - 500ms DC interrupt (residual%) 0% - 5s
IEC 61000-4-16:1998	Differential mode: 150 Vrms. Common mode: 300V r.m.s. Freq: 16.7 Hz, 50 Hz or 60 Hz
IEC 61000-4-17:1999	Test level: 15 % of rated dc. value Test frequency: 100/120Hz, sinusoidal waveform
IEC 61000-4-18:2006	Voltage oscillation frequency: 1MHz Differential mode: 1kV peak voltage; Common mode 2,5kV peak voltage
Gradual Startup	Shut-down ramp: 60s Power off: 5min. Start-up ramp: 60s
CISPR11:2009 (below 1GHz)	Radiated emission Limits: 30 to 230 MHz - 50dB (μV/m) quasi peak at 3m 230 to 1000 MHz - 57dB (μV/m) quasi peak at 3m
CISPR22:2008 (above 1GHz)	Radiated emission Limits: 1 to 3 GHz – 56 dB (μ V/m) average; 76 dB (μ V/m) peak at 3 m 3 to 6 GHz – 60 dB (μ V/m) average; 80 dB (μ V/m) peak at 3 m
CISPR22:2008	Conducted emission Limits: 0.15 to 0.50 MHz - 79dB (μV) quasi peak; 66dB (μV) average 0.5 to 30 MHz - 73dB (μV) quasi peak; 60dB (μV) average
Safety tests	
Safety	IEC 60255-27
IEC 60255-5	Impulse – 5kV Dielectric withstand – 2.2 kVrms Insulation resistance > 100MΩ @ 500 Vdc
Environmental tests	
IEC 60068-2-1	-40°C, 16 hours (Cold operational)
IEC 60068-2-1	-40°C, 16 hours (Cold storage)
IEC 60068-2-2	+85°C, 16 hours (Dry heat operational)
IEC 60068-2-2	+85°C, 16 hours (Dry heat storage)
IEC 60068-2-30	+25°C ± 3 °C-97% -2% +3% RH +55°C ±2°C -93% ±3% RH 6 of 24 hours (12h + 12h) cycles
IEC 60068-2-14	-40°C to 55°C / 9 hours / 2 cycles (Change of temperature)
IEC 60068-2-78	+40°C ±2°C -93% ±3% RH -10 days
IEC 60255-21-1	Vibration Response and Endurance Class 2
IEC 60255-21-2	Shock Response and Endurance Class 1
IEC 60255-21-2	Bump Class 1
IEC 60255-21-3	Seismic Class 2

MU320E is a product RoHS 3 Compliant

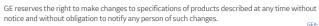
MU320 Ordering

Model Type N	1U320 *	* * *	* * *	* * X	04	S E	MU320 Integrated Merging Unit - Extented Version
Slot A - Power Supply	3						110-250 Vdc / 110-240 Vac
Slot B - Hardware Options		L					Two duplex LC-type connector 100BASE-FX Ethernet interfaces
Slot C - Binary I/O		B3					16 x 24V/48V/125V/250V binary inputs
		B4					6 x 24V/48V/125V/250V binary inputs and 8 x binary outputs
		B5					6 x 24V/48V/125V/250V binary inputs and 4 x Form C + 2 x NO binary outputs
		B6					6 x 24/48/125/250 V binary inputs and 8 x High Speed Form A binary outputs
Slot D - Binary I/O		B3					16 x 24V/48V/125V/250V binary inputs
		B4					6 x 24V/48V/125V/250V binary inputs and 8 x binary outputs
		B5					6 x 24V/48V/125V/250V binary inputs and 4 x Form C + 2 x NO binary outputs
		B6					6 x 24/48/125/250 V binary inputs and 8 x High Speed Form A binary outputs
Slot E – Binary I/OSlot 1			B3				16 x 24V/48V/125V/250V binary inputs
			B4				6 x 24V/48V/125V/250V binary inputs and 8 x binary outputs
			B5				6 x 24V/48V/125V/250V binary inputs and 4 x Form C + 2 x NO binary outputs
			B6				6 x 24/48/125/250 V binary inputs and 8 x High Speed Form A binary outputs
Slot F – Binary I/OSlot 2			B3				16 x 24V/48V/125V/250V binary inputs
			B4				6 x 24V/48V/125V/250V binary inputs and 8 x binary outputs
			B5				6 x 24V/48V/125V/250V binary inputs and 4 x Form C + 2 x NO binary outputs
			B6				6 x 24/48/125/250 V binary inputs and 8 x High Speed Form A binary outputs
Slot G – Flexible I/O options			B3				16 x 24V/48V/125V/250V binary inputs
			B4				6 x 24V/48V/125V/250V binary inputs and 8 x binary outputs
			B5				6 x 24V/48V/125V/250V binary inputs and 4 x Form C + 2 x NO binary outputs
			B6				6 x 24/48/125/250 V binary inputs and 8 x High Speed Form A binary outputs
			P1				4 x VT 115V and 4 x CT 1 A RMS protection analog inputs
			P5				4 x VT 115V and 4 x CT 5 A RMS protection analog inputs
			XX				Not Installed
Slot H – Flexible I/O options				3			16 x 24V/48V/125V/250V binary inputs
				4			6 x 24V/48V/125V/250V binary inputs and 8 x binary outputs
				5			6 x 24V/48V/125V/250V binary inputs and 4 x Form C + 2 x NO binary outputs
				6			6 x 24/48/125/250 V binary inputs and 8 x High Speed Form A binary outputs
							4 x VT 115V and 4 x CT 1 A RMS protection analog inputs
			P				
				5			4 x VT 115V and 4 x CT 5 A RMS protection analog inputs
Functions and Application			Х	X			Not Installed
Functions and Application				A			Standard Integrated Merging Unit
Decenved				В			PRP redundant Integrated Merging Unit
Reserved				Х			Not Used
Firmware Version					04		Latest available firmware - 04
Coating						S	Standard Conformal Coating
Hardware Design Suffix						E	Extended version

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